

Description

The 74AHC04 provides provides six independent inverters with standard push-pull outputs. The device is designed for operation with a power supply range of 2.0V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment.

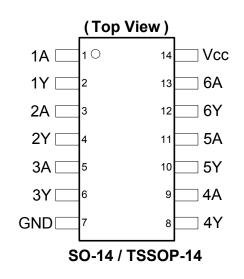
The gates perform the Boolean function:

 $Y = \overline{A}$

Features

- Wide Supply Voltage Range from 2.0V to 5.5V
- Outputs Sink or Source 8 mA at V_{CC} = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- Inputs can be driven by 3.3V or 5.5V allowing for voltage translation applications.
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- General Purpose Logic
- Wide array of products such as:
 - PCs, Networking, Notebooks, Netbooks
 - Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set Top Box

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

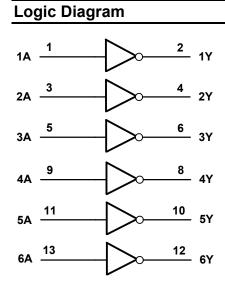
Click for Ordering Information

74AHC04 HEX INVERTERS



Pin Descriptions

Pin		
Number	Pin Name	Function
1	1A	Data Input
2	1Y	Data Output
3	2A	Data Input
4	2Y	Data Output
5	3A	Data Input
6	3Y	Data Output
7	GND	Ground
8	4Y	Data Output
9	4A	Data Input
10	5Y	Data Output
11	5A	Data Input
12	6Y	Data Output
13	6A	Data Input
14	Vcc	Supply Voltage



Function Table

Input	Output
Α	Y
L	Н
Н	L

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM Human Body Model ESD Protection		2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
I _{IK} Input Clamp Current V _I < -0.5V		-20	mA
I _{OK} Output Clamp Current V _O < -0.5V		-20	mA
I _{OK} Output Clamp Current V _O > V _{CC} +0.5V		25	mA
I _O Continuous Output Current -0.5V < V _O V _{CC} +0.5V		+/- 25	mA
Icc	Continuous Current Through V _{CC}	75	mA
I _{GND} Continuous Current Through GND		-75	mA
T _J Operating Junction Temperature		-40 to +150	°C
T _{STG} Storage Temperature		-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
Vcc	Supply Voltage		2.0	5.5	V
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V _{CC}	V
Δt/ΔV	Input Transition Rise or Fall Rate	V _{CC} = 3.0V to 3.6V		100	ns/V
ΔυΔν		V _{CC} = 4.5V to 5.5V		20	115/ V
T _A	Operating Free-Air Temperature		-40	+125	°C

5. Unused inputs should be held at V_{cc} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Ourseland	Demonstern	Test Canditions		T _A = -40°	C to +85°C	T _A = -40°C	to +125°C	11
Symbol	Parameter	Test Conditions	Vcc	Min	Max	Min	Мах	Unit
			2.0V	1.5		1.5		
VIH	High-Level Input Voltage		3.0V	2.1		2.1		V
	Voltage		5.5V	3.85		3.85		
			2.0V		0.5		0.5	
VIL	Low-Level Input Voltage		3.0V		0.9		0.9	V
	Voltage		5.5V		1.65		1.65	
	High-Level Output Voltage	I _{OH} = -50μA	2.0V	1.9		1.9		
		I _{OH} = -50µА	3.0V	2.9		2.9		
V _{OH}		I _{OH} = -50μA	4.5V	4.4		4.4		V
		I _{OH} = -4mA	3.0V	2.48		2.40		
		I _{OH} = -8mA	4.5V	3.80		3.70		
		I _{OL} = 50μΑ	2.0V		0.1		0.1	
		I _{OL} = 50μΑ	3.0V		0.1		0.1	
V _{OL}	Low-Level Output Voltage	I _{OL} = 50μΑ	4.5V		0.1		0.1	V
		I _{OL} = 4mA	3.0V		0.44		0.55	
		I _{OL} = 8mA	4.5V		0.44		0.55	
lı	Input Current	V _I =GND to 5.5V	3.6V		±1		±2	μA
lcc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	3.6V		20		40	μA

Operating Characteristics

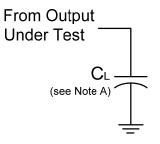
	Parameter	Test Conditions	V _{CC} = 2.0V Typ	V _{CC} = 3.3V Typ	V _{CC} = 5V Typ	Unit
C _{pd}	Power Dissipation Capacitance per Gate	f = 1MHz	9.7	11.2	15	pF
Ci	Input Capacitance	V _i = V _{CC} – or GND	4.0	4.0	4.0	pF



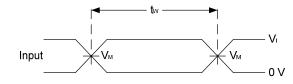
Switching Characteristics

Symbol Parameter		Test	Vaa	T _A = +25°C		-40°C to +85°C		-40°C to +125°C		Unit	
Symbol	Falameter	Conditions	V _{cc}	Min	Тур	Мах	Min	Max	Min	Max	Unit
		Figure 1	3.0V to 3.6V	0.5	4.0	8.5	0.5	10.5	0.5	11.0	
	Propagation	C _L = 15pF	4.5V to 5.5V	0.5	3.0	5.5	0.5	6.5	0.5	7.0	20
t _{PD}	Delay A_N to Y_N	Figure 1	3.0V to 3.6V	0.5	6.0	11.4	0.5	13.0	0.5	14.5	ns
		$C_L = 50 pF$	4.5V to 5.5V	0.5	4.5	7.5	0.5	8.5	0.5	9.5	

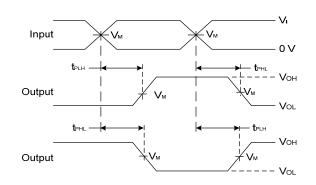
Parameter Measurement Information



N	Inputs		N N	0
V _{cc}	VI	t _r /t _f	VM	CL
3.3V -3.6V	V _{CC}	3ns	V _{CC} /2	15pF, 50pF
4.5V to 5.5V	V _{CC}	3ns	V _{CC} /2	15pF, 50pF



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

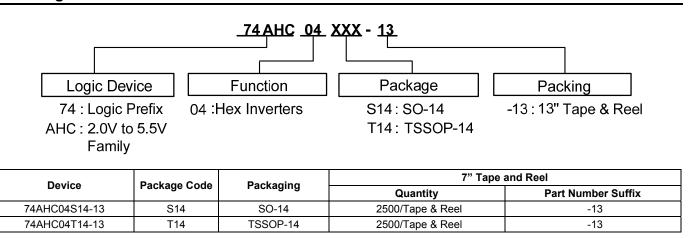
Figure 1 Load Circuit and Voltage Waveforms

Notes: A . Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate \leq 1 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD}

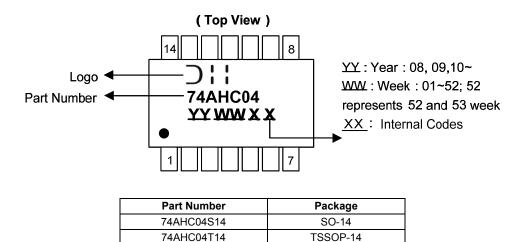


Ordering Information



Marking Information

(1) SO-14, TSSOP-14



Pb

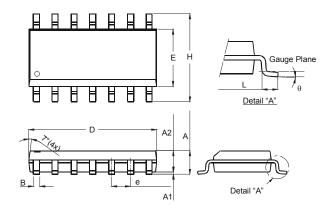
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Package Outline Dimensions (All dimensions in mm.)

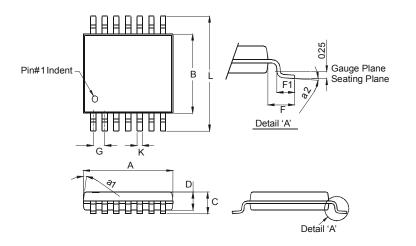
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



	SO-14				
Dim	Min	Max			
Α	1.47	1.73			
A1	0.10	0.25			
A2	1.45	Тур			
В	0.33	0.51			
D	8.53	8.74			
Е	3.80	3.99			
е	1.27	Тур			
н	5.80	6.20			
L	0.38	1.27			
θ	0°	8°			
All Di	mensions	s in mm			

Package Type: TSSOP-14



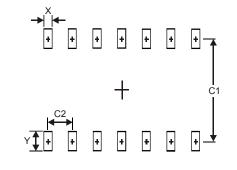
	TSSOP-1	4	
Dim	Min	Max	
a1	7° (4X)	
a2	0°	8°	
Α	4.9	5.10	
В	4.30	4.50	
С	_	1.2	
D	0.8	1.05	
F	1.00	Тур	
F1	0.45	0.75	
G	0.65	Тур	
κ	0.19 0.30		
L	6.40	Тур	
All Dir	nensions	s in mm	



Suggested Pad Layout

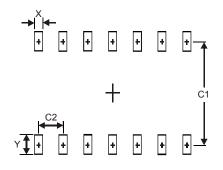
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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